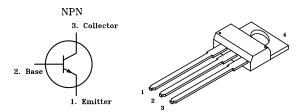
Transistor





RoHS Compliant



Pin Configuration

- Rase
- Collector
- 3. Emitter
- 4. Collector

Description:

A silicon Darlington transistor in a T0-220 case intended for general purpose amplifier and low speed switching applications.

Absolute Maximum Ratings:

 $\begin{array}{lll} \text{Base Current, I}_{\text{B}} & : 1 \text{A} \\ \text{Collector Dissipation (T}_{\text{C}} = +25^{\circ}\text{C), P}_{\text{C}} & : 80 \text{W} \\ \text{Operating Junction Temperature, T}_{\text{J}} & : +150^{\circ}\text{C} \\ \end{array}$

Storage Temperature Range, T_{stg} : -65°C to +150°C Thermal Resistance, Junction-to-Case, $R_{th,IC}$: 1.56°C/W

Electrical Characteristics: $(T_A = +25^{\circ}C \text{ unless otherwise specified})$

Parameter	Symbol	Test Conditions	Min.	Тур	Max.	Unit		
Collector-Emitter Sustaining Voltage	VCEO(sus)	$I_{\rm C}$ = 30mA, I _B = 0, Note 1	80	-	-	V		
Collector Cut-Off Current	I _{CBO}	V _{CB} = 80V, IE = 0	-	-	50	μA		
	I _{CEO}	$V_{CE} = 40V, I_{B} = 0$	-	-	50	uA		
Emitter Cut-Off Current	І ЕВО	V _{EB} = 5V, I _C = 0	-	-	8	mA		
DC Current Gain	h _{FE}	$I_{\rm C} = 3A, V_{\rm CE} = 4V$	1,000	-	20,000	-		
		$I_{\rm C} = 8A, V_{\rm CE} = 4V$	200	-	-	-		
Collector-Emitter Saturation Voltage	V _{CE(sat)}	$I_C = 3A$, $I_B = 6mA$, Note 1	-	-	2			
		$I_{\rm C}$ = 8A, $I_{\rm B}$ = 80mA, Note 1	-	-	2.5	v		
Base-Emitted Saturation Voltage	V _{BE(on)}	$I_{\rm C}$ = 8A, $I_{\rm B}$ = 4V, Note 1	-	-	2.8			
Small-Signal Current Gain	h _{fe}	$I_C = 3A$, $V_{CE} = 4V$, $f = 1MHz$	4	-	-	-		

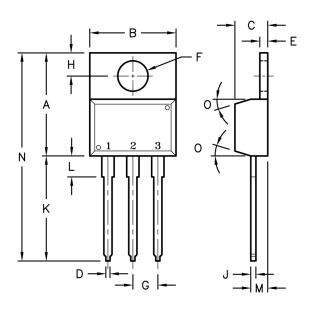
Note 1. Pulse Test: Pulse Width = 300µs, Duty Cycle = 1.5%.

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Transistor





Dim.	Min.	Max.		
Α	14.42	16.51		
В	9.63	10.67		
С	3.56	4.83		
D	-	0.9		
E	1.15	1.4		
F	3.75	3.88		
G	2.29	2.79		
Н	2.54	3.43		
J	-	0.56		
K	12.7	14.73		
L	2.8	4.07		
М	2.03	2.92		
N	-	31.24		
0	7°	7°		

Dimensions: Millimetres

Pin Configuration

- 1. Base
- 2. Collector
- 3. Emitter
- 4. Collector

Part Number Table

Description	Part Number		
Transistor, NPN, 8A, 80V, TO-220	TIP101		

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